

MA360

Silicon epitaxial planer type

For UHF and VHF electronic tuners

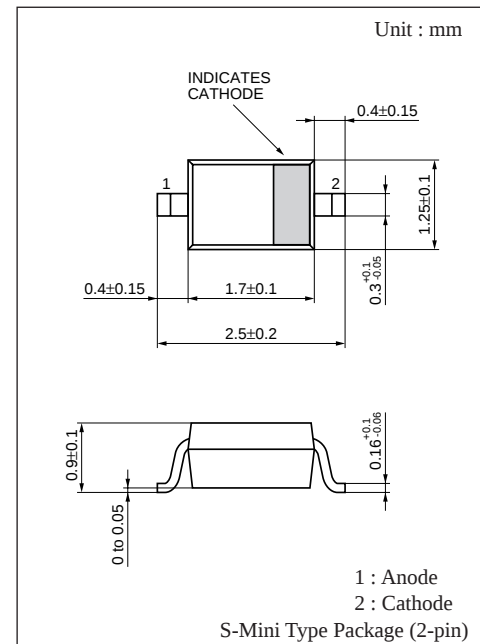
■ Features

- Large capacity variation ratio
- Small series resistance r_D

■ Absolute Maximum Ratings (Ta= 25°C)

Parameter	Symbol	Rating	Unit
Reverse voltage (DC)	V_R	30	V
Peak reverse voltage	V_{RM}^*	35	V
Forward current (DC)	I_F	20	mA
Junction temperature	T_j	150	°C
Storage temperature	T_{stg}	- 55 to +150	°C

* $R_L \approx 10k\Omega$



Marking Symbol : 6A

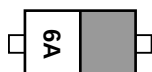
■ Electrical Characteristics (Ta= 25°C)

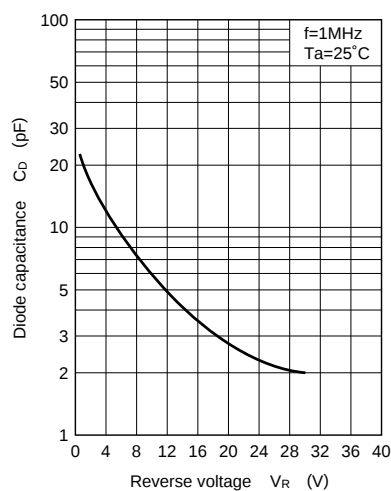
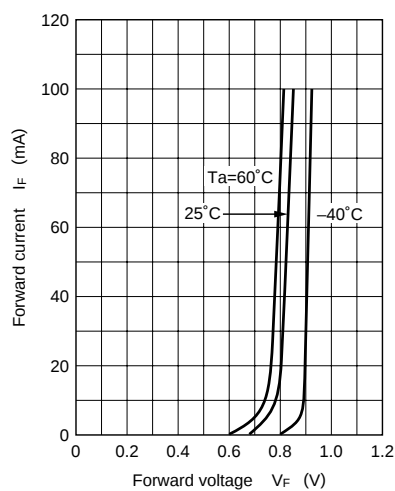
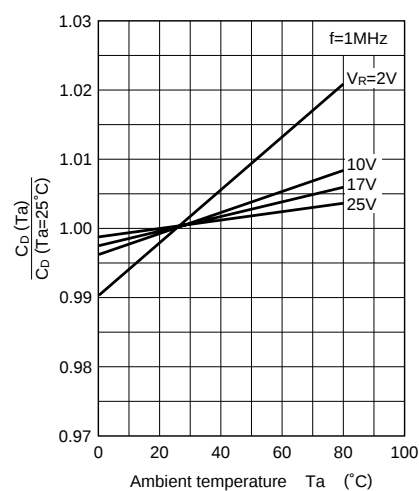
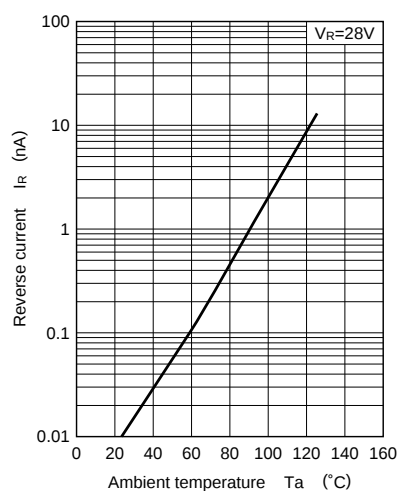
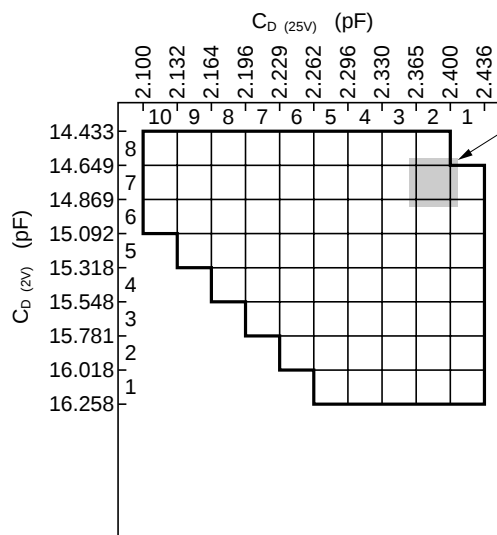
Parameter	Symbol	Condition	min	typ	max	Unit
Reverse current (DC)	I_R	$V_R = 28V$			10	nA
Diode capacitance	$C_{D(2V)}$	$V_R = 2V, f = 1MHz$	14.360		16.340	pF
	$C_{D(25V)}$	$V_R = 25V, f = 1MHz$	2.089		2.448	pF
	$C_{D(10V)}$	$V_R = 10V, f = 1MHz$	5.433		6.369	pF
	$C_{D(17V)}$	$V_R = 17V, f = 1MHz$	2.945		3.452	pF
Capacitance ratio	$C_{D(2V)}/C_{D(25V)}$		5.95		7.26	—
Diode capacitance deviation	ΔC	$C_D (2V) (10V) (17V) (25V)$			2	%
Series resistance	r_D^{*1}	$C_D = 9pF, f = 470MHz$			0.6	Ω

Note 1. Rated input/output frequency : 470MHz

2. *1 : r_D measurement device : YHP MODEL 4191A RF IMPEDANCE ANALYZER

■ Marking



$C_D - V_R$  $I_F - V_F$  $C_D - T_a$  $I_R - T_a$  **C_D rank classification****Primary rank classification**

Note: Tracking guarantee range (Capacitance difference 2.0%)

Secondary rank classification